

SNx5ALS180 差動ドライバとレシーバのペア

1 特長

- TIA/EIA-422-B、TIA/EIA-485-A の要件を満たしているか、それを上回っています。¹ ITU 勧告 V.11 です。
- 高速の高度な低消費電力ショットキー回路
- シリアルとパラレルの両方のアプリケーションでの 25Mbaud 動作に対応
- デバイス間の低スキュー: 6ns (最大)
- 小さい消費電流要件: 30mA 以下
- デュアル V_{CC} およびデュアル GND を備えた個別のドライバおよびレシーバ I/O ピン
- 広い正および負の入力 / 出力バス電圧範囲
- ドライバ出力能力: $\pm 60\text{mA}$
- サーマル・シャットダウン保護機能
- ドライバの正および負の電流制限
- レシーバ入力インピーダンス: $12\text{k}\Omega$ 以上
- レシーバ入力感度: 最大 $\pm 200\text{mV}$
- レシーバ入力ヒステリシス: 60mV (標準値)
- 単一の 5V 電源で動作
- グリッチ・フリーのパワーアップ / パワーダウン保護機能

2 概要

SN65ALS180 および SN75ALS180 差動ドライバおよびレシーバのペアは、マルチポイント・バス伝送ラインでの双方向データ通信用に設計された IC です。これらのデバイスは平衡伝送ライン用に設計されており、TIA/EIA-422-B、TIA/EIA-485-A、ITU 勧告 V.11 を満たしています。

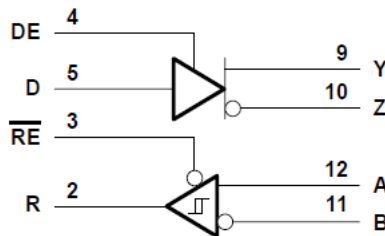
SN65ALS180 および SN75ALS180 は、3 ステート差動ライン・ドライバと差動入力ライン・レシーバを統合しており、どちらも 5V 単一電源で動作します。ドライバとレシーバはそれぞれアクティブ High、アクティブ Low のイネーブルを備えており、それらのイネーブルを外部で互いに接続することで、方向制御として機能させることができます。ドライバの差動出力とレシーバの差動入力、自由度が増すように個別の端子に接続されており、ドライバがディセーブルされた場合、または $V_{CC} = 0$ の場合、バスへの負荷が最小化されるように設計されています。

これらのポートは広い正および負の同相モード電圧範囲を持っているため、本デバイスはパーティライン・アプリケーションに適しています。

パッケージ情報

部品番号	パッケージ ⁽¹⁾	本体サイズ (公称)
SNx5ALS176	D (SOIC)	8.65mm × 3.91mm
	N (PDIP)	19.3mm × 6.35mm

(1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。



論理図 (正論理)

¹ これらのデバイスは、ジェネレータ競合テスト (3.4.2 項) とジェネレータ電流制限 (3.4.3 項) を除き、TIA/EIA-485-A の要件を満たしているか、それを上回っています。適用されるテスト電圧範囲は、SN75ALS180 では $-6\text{V} \sim 8\text{V}$ 、SN65ALS180 では $-4\text{V} \sim 8\text{V}$ で、



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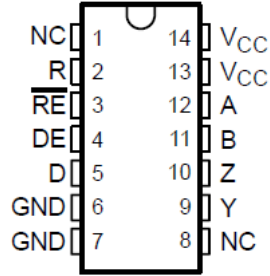
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3 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision G (April 2003) to Revision H (January 2023)	Page
• ドキュメントを最新のテキサス・インスツルメンツ・フォーマットに変更.....	1
• Deleted the Package thermal impedance from the <i>Absolute Maximum Ratings</i>	4
• Added the <i>Thermal Information</i> table.....	4
• Changed the <i>Typical Characteristics</i> graphs.....	8

4 Pin Configuration and Functions



NC – No internal connection

**图 4-1. SN65ALS180 D Package
 SN75ALS180 D or N Package
 (Top View)**

表 4-1. Pin Functions

NO	Name	Type	Description
1	NC	-	No Internal connection
2	R	O	Receive data output
3	RE	I	Receiver enable, active low
4	DE	I	Driver enable, active high
5	D	I	Driver data input
6, 7	GND	GND	Device ground
8	NC	-	No Internal connection
9	Y	O	Digital bus output, Y (Complementary to Z)
10	Z	O	Digital bus output, Z (Complementary to Y)
11	A	I	Bus input, A (complementary to B)
12	B	I	Bus input, B (complementary to A)
13, 14	V _{CC}	SUPPLY	4.75V to 5.25V supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾		7	V
	Voltage range at any bus terminal	-10	15	V
V _I	Enable input voltage		5.5	V
T _J	Operating virtual junction temperature		150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C
T _{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.

5.2 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.75	5	5.25	V
V _I or V _{IC}	Voltage at any bus terminal (separately or common mode)			12 -7	V
V _{IH}	High-level input voltage	D, DE, and RE	2		V
V _{IL}	Low-level input voltage	D, DE, and RE		0.8	V
V _{ID}	Differential input voltage ⁽¹⁾			±12	V
I _{OH}	High-level output current	Driver		-60	mA
		Receiver		-400	µA
I _{OL}	Low-level output current	Driver		60	mA
		Receiver		8	
T _A	Operating free-air temperature	SN65ALS180	-40	85	°C
		SN75ALS180	0	70	

- (1) Differential-input/output bus voltage is measured at the noninverting terminal, A/Y, with respect to the inverting terminal, B/Z.

5.3 Thermal Information

THERMAL METRIC ⁽¹⁾		N (PDIP)	D (SOIC) (SN65 Devices)	D (SOIC) (SN75 Devices)	UNIT
		14-Pins	14-Pins	14-Pins	
R _{θJA}	Junction-to-ambient thermal resistance	53.4	93.2	83.7	°C/W
R _{θJC(top)}	Junction-to-case thermal resistance	40	47.5	39.8	°C/W
R _{θJB}	Junction-to-board thermal resistance	33.3	49.4	39.7	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	1	11.2	7.2	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	33	48.9	39.7	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.4 Electrical Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP ⁽²⁾	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = -18 mA				-1.5	V
V _O	Output voltage	I _O = 0		0		6	V
V _{OD1}	Differential output voltage	I _O = 0		1.5		6	V
V _{OD2}	Differential output voltage	R _L = 100 Ω	See 6-1	1/2V _{OD1} or 2 ⁽³⁾			V
		R _L = 54 Ω	See 6-1	1.5	2.5	5	
V _{OD3}	Differential output voltage	V _{test} = -7 V to 12 V,	See 6-2	1.5		5	V
Δ V _{OD}	Change in magnitude of differential output voltage ⁽⁴⁾	R _L = 54 Ω or 100 Ω	See 6-1			±0.2	V
V _{OC}	Common-mode output voltage	R _L = 54 Ω or 100 Ω	See 6-1			3 -1	V
Δ V _{OC}	Change in magnitude of common-mode output voltage ⁽⁴⁾	R _L = 54 Ω or 100 Ω	See 6-1			±0.2	V
I _O	Output current	Output disabled ⁽⁶⁾		V _O = 12 V		1	mA
				V _O = -7 V		-0.8	
I _{IH}	High-level input current	V _I = 2.4 V				20	μA
I _{IL}	Low-level input current	V _I = 0.4 V				-400	μA
I _{OS}	Short-circuit output current ⁽⁵⁾	V _O = -6 V	SN75ALS180			-250	mA
		V _O = -4 V	SN65ALS180			-250	
		V _O = 0	All			-150	
		V _O = V _{CC}	All			250	
		V _O = 8 V	All			250	
I _{CC}	Supply current	No load		Driver outputs enabled, Receiver disabled	25	30	mA
					Outputs disabled	19	

- (1) The power-off measurement in TIA/EIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.
- (2) All typical values are at V_{CC} = 5 V, T_A = 25°C.
- (3) The minimum V_{OD2} with 100-Ω load is either 1/2 V_{OD2} or 2 V, whichever is greater.
- (4) Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.
- (5) Duration of the short circuit should not exceed one second for this test.
- (6) This applies for both power on and off; refer to TIA/EIA-485-A for exact conditions. The TIA/EIA-422-B limit does not apply for a combined driver and receiver terminal.

5.5 Switching Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS			MIN	TYP ⁽¹⁾	MAX	UNIT
t _{d(OD)}	Differential output delay time	R _L = 54 Ω	C _L = 50 pF,	See 6-3	3	8	13	ns
	Pulse skew (t _{d(ODH)} - t _{d(ODL)})	R _L = 54 Ω	C _L = 50 pF,	See 6-3		1	6	ns
t _{t(OD)}	Differential output transition time	R _L = 54 Ω	C _L = 50 pF,	See 6-3	3	8	13	ns
t _{PZH}	Output enable time to high level	R _L = 110 Ω	See 6-4			23	50	ns
t _{PZL}	Output enable time to low level	R _L = 110 Ω	See 6-5			19	24	ns
t _{PHZ}	Output disable time from high level	R _L = 110 Ω	See 6-4			8	13	ns
t _{PLZ}	Output disable time from low level	R _L = 110 Ω	See 6-5			8	13	ns

- (1) All typical values are at V_{CC} = 5 V and T_A = 25°C.

5.6 Symbol Equivalents

DATA-SHEET PARAMETER	TIA/EIA-422-B	TIA/EIA-485-A
V_O	V_{oa}, V_{ob}	V_{oa}, V_{ob}
$ V_{OD1} $	V_o	V_o
$ V_{OD2} $	$V_t(R_L = 100 \Omega)$	$V_t(R_L = 54 \Omega)$
$ V_{OD3} $		V_t (test termination measurement 2)
V_{test}		V_{tst}
$\Delta V_{OD} $	$ V_t - V_t $	$ V_t - V_t $
V_{OC}	$ V_{os} $	$ V_{os} $
$\Delta V_{OC} $	$ V_{os-} - V_{os} $	$ V_{os-} - V_{os} $
I_{os}	$ I_{sa} , I_{sb} $	
I_o	$ I_{xa} , I_{xb} $	I_{ia}, I_{ib}

5.7 Electrical Characteristics - Receivers

over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	V _O = 2.7 V,	I _O = -0.4 mA				0.2	V
V _{IT-}	Negative-going input threshold voltage	V _O = 0.5 V,	I _O = 8 mA		-0.2 ⁽²⁾			V
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})					60		mV
V _{IK}	Enable-input clamp voltage	I _I = -18 mA					-1.5	V
V _{OH}	High-level output voltage	V _{ID} = 200 mV,	I _{OH} = -400 μA,	See 6-6	2.7			V
V _{OL}	Low-level output voltage	V _{ID} = -200 mV,	I _{OL} = 8 mA,	See 6-6			0.45	V
I _{OZ}	High-impedance-state output current	V _O = 0.4 V to 2.4 V					±20	μA
I _I	Line input current	Other input = 0 V ⁽³⁾	V _I = 12 V				1	mA
			V _I = -7 V				-0.8	
I _{IH}	High-level enable-input current	V _{IH} = 2.7 V					20	mA
I _{IL}	Low-level enable-input current	V _{IL} = 0.4 V					-100	mA
r _i	Input resistance				12			kΩ
I _{OS}	Short-circuit output current	V _{ID} = 200 mV,	V _O = 0		-15		-85	mA
I _{CC}	Supply current	No load	Receiver outputs enabled, Driver inputs disabled			19	30	mA
			Outputs disabled			19	26	

(1) All typical values are at V_{CC} = 5 V, T_A = 25°C.

(2) The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

(3) This applies for both power on and power off. Refer to TIA/EIA-485-A for exact conditions.

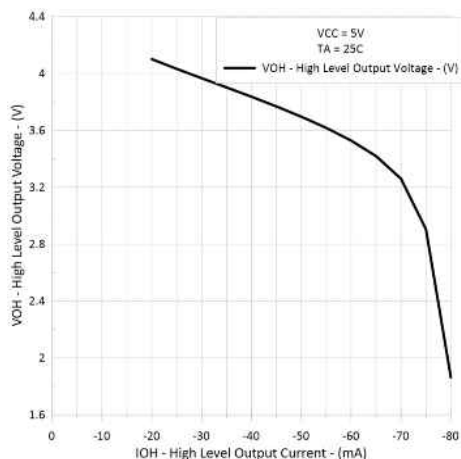
5.8 Switching Characteristics - Receivers

over recommended ranges of supply voltage and operating free-air temperature

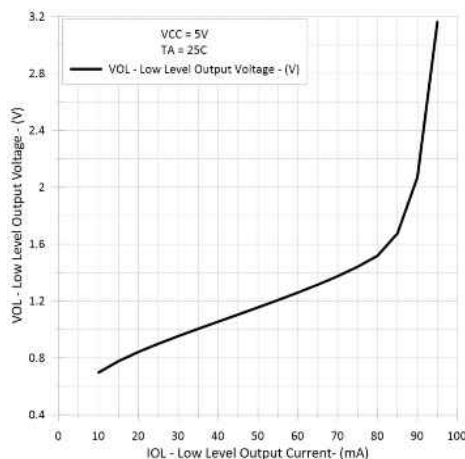
PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	V _{ID} = -1.5 V to 1.5 V, See 6-7	C _L = 15 pF,	9	14	19	ns
t _{PHL}	Propagation delay time, high- to low-level output	V _{ID} = -1.5 V to 1.5 V, See 6-7	C _L = 15 pF,	9	14	19	ns
	Skew (t _{PHL} - t _{PLH})	V _{ID} = -1.5 V to 1.5 V, See 6-7	C _L = 15 pF,		2	6	ns
t _{PZH}	Output enable time to high level	C _L = 15 pF,	See 6-8		7	14	ns
t _{PZL}	Output enable time to low level	C _L = 15 pF,	See 6-8		7	14	ns
t _{PHZ}	Output disable time from high level	C _L = 15 pF,	See 6-8		20	35	ns
t _{PLZ}	Output disable time from low level	C _L = 15 pF,	See 6-8		8	17	ns

(1) All typical values are at V_{CC} = 5 V, T_A = 25°C.

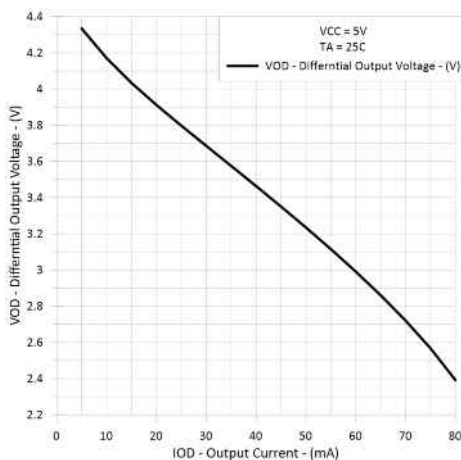
5.9 Typical Characteristics



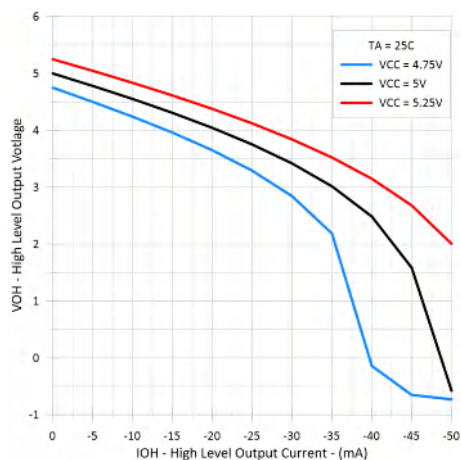
5-1. Drivers High-Level Output Voltage vs High-Level Output Voltage



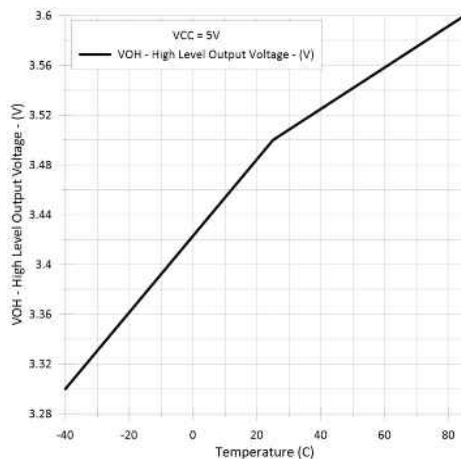
5-2. Drivers Low-Level Output Voltage vs Low-Level Output Current



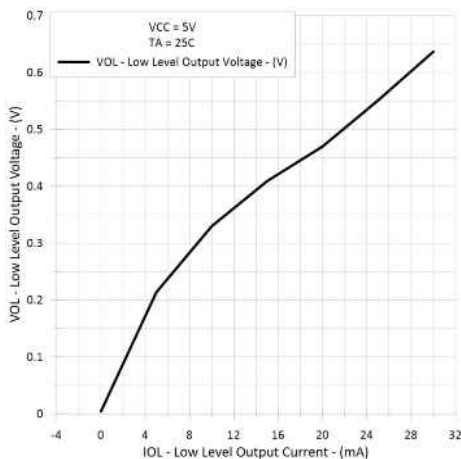
5-3. Drivers Differential Output Voltage vs Output Current



5-4. Receivers High-Level Output Voltage vs High-Level Output Current

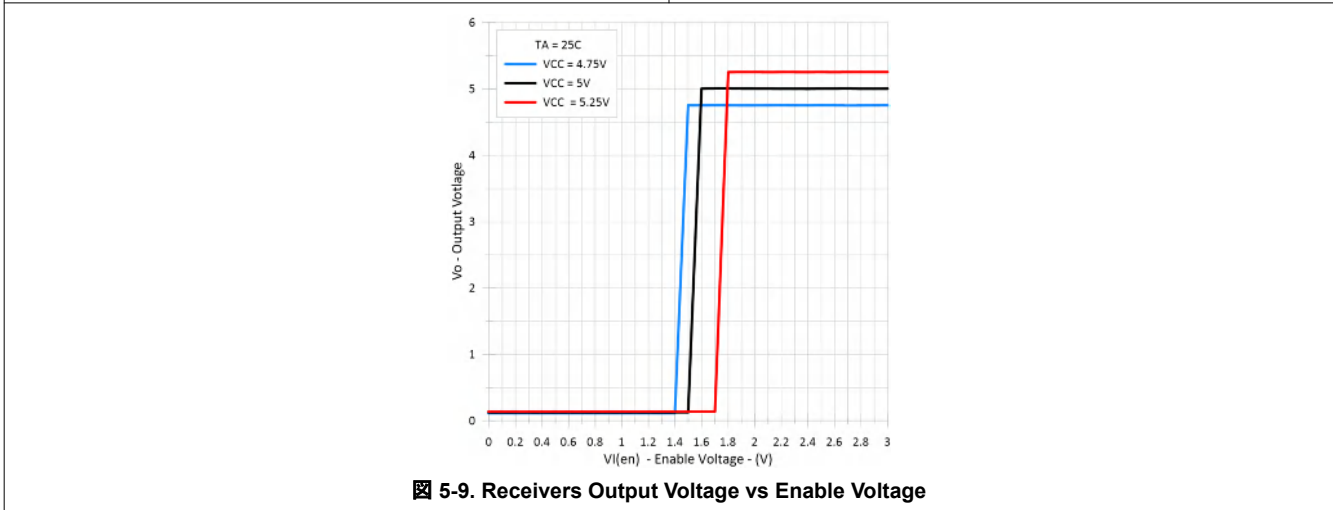
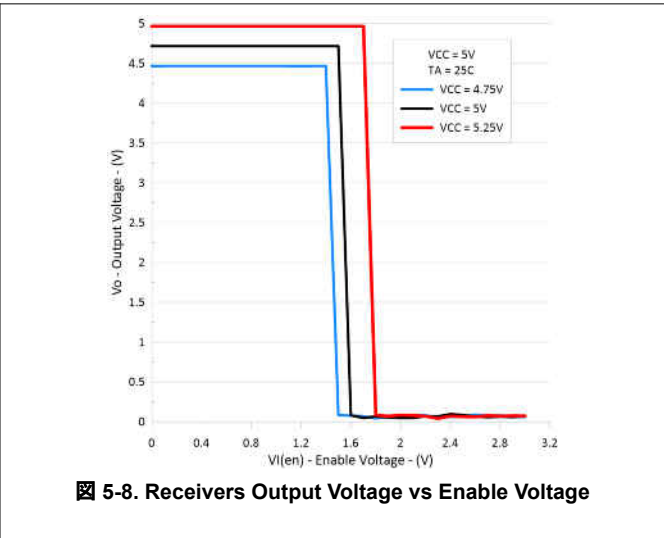
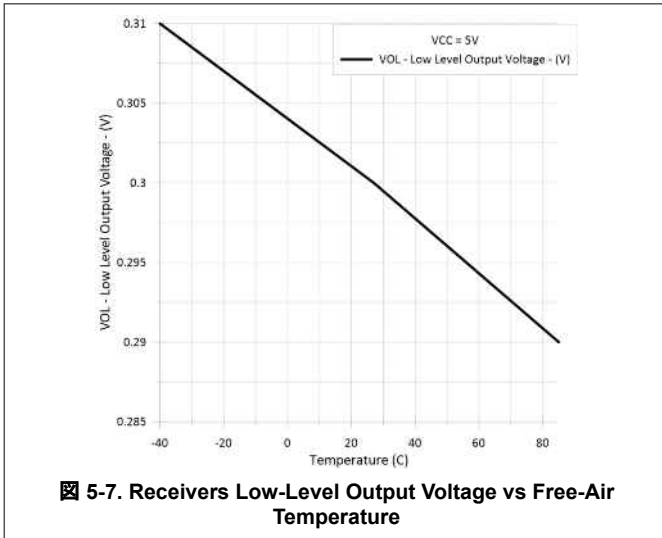


5-5. Receivers High-Level Output Voltage vs Free-Air Temperature



5-6. Receivers Low-Level Output Voltage vs Low-Level Output Current

5.9 Typical Characteristics (continued)



6 Parameter Measurement Information

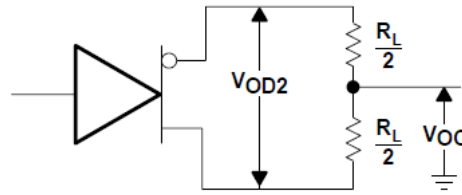


FIG 6-1. Driver V_{OD} and V_{OC}

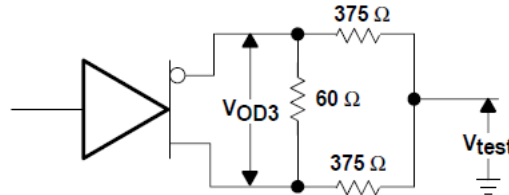
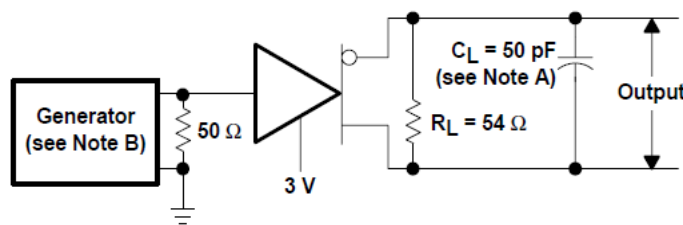
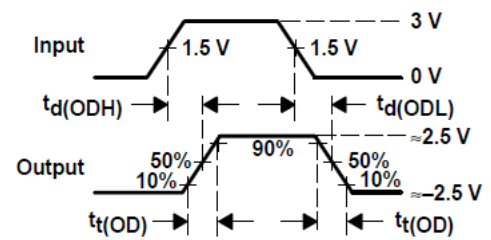


FIG 6-2. Driver V_{OD3}



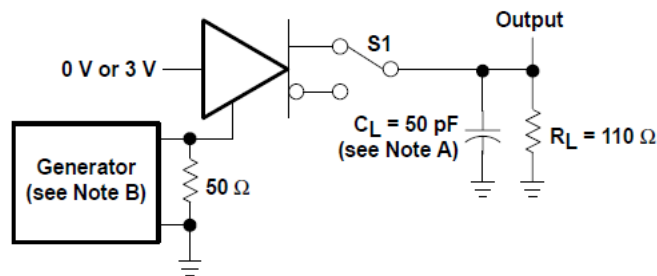
TEST CIRCUIT



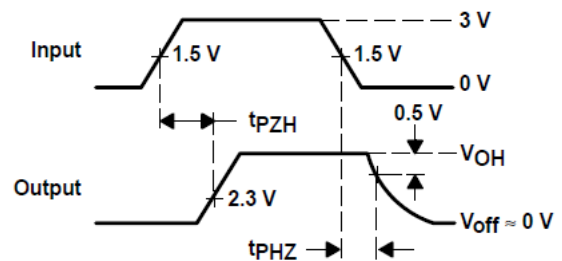
VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 6 ns, $t_f \leq$ 6ns, $Z_0 = 50 \Omega$.

FIG 6-3. Driver Test Circuit and Voltage Waveforms



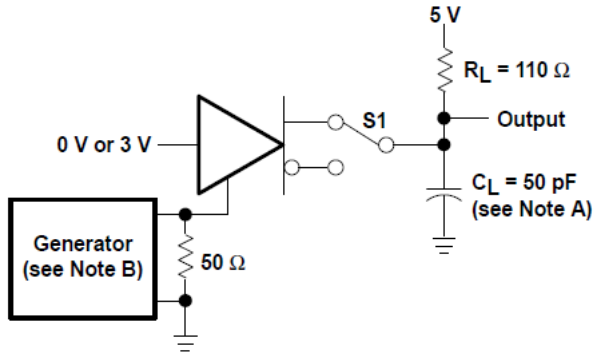
TEST CIRCUIT



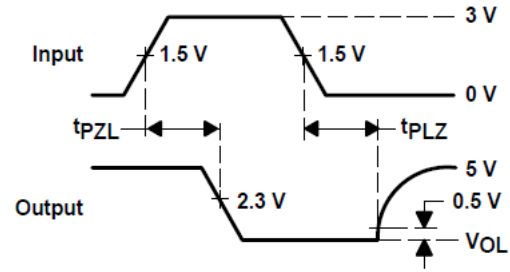
VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_r \leq$ 6 ns, $t_f \leq$ 6ns, $Z_0 = 50 \Omega$.

FIG 6-4. Driver Test Circuit and Voltage Waveforms



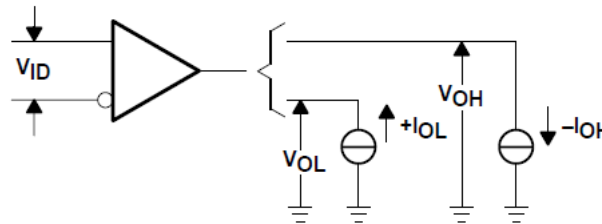
TEST CIRCUIT



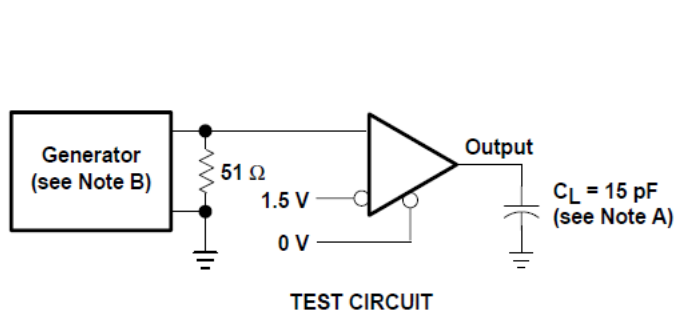
VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

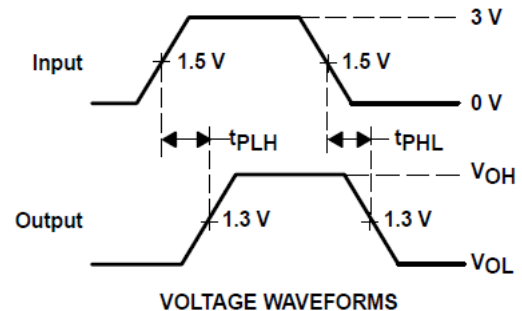
6-5. Driver Test Circuit and Voltage Waveforms



6-6. Receiver V_{OH} and V_{OL}



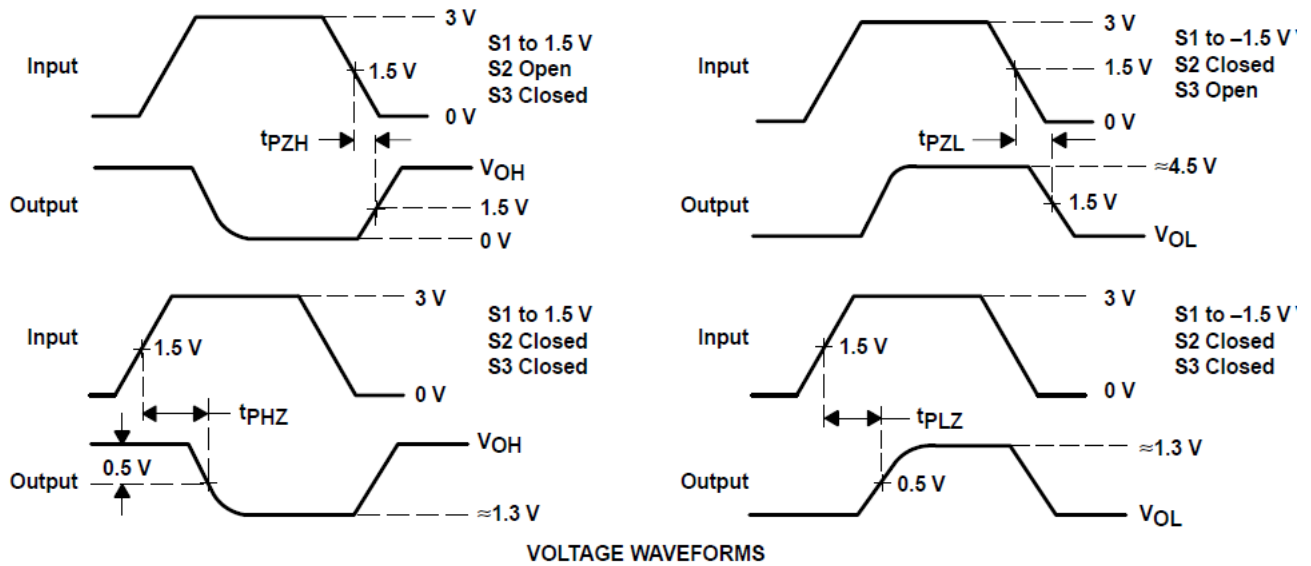
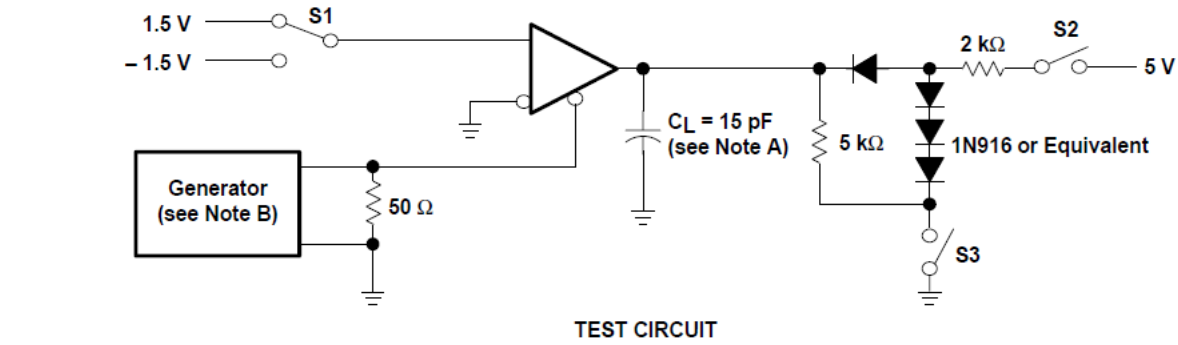
TEST CIRCUIT



VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

6-7. Receiver Test Circuit and Voltage Waveforms

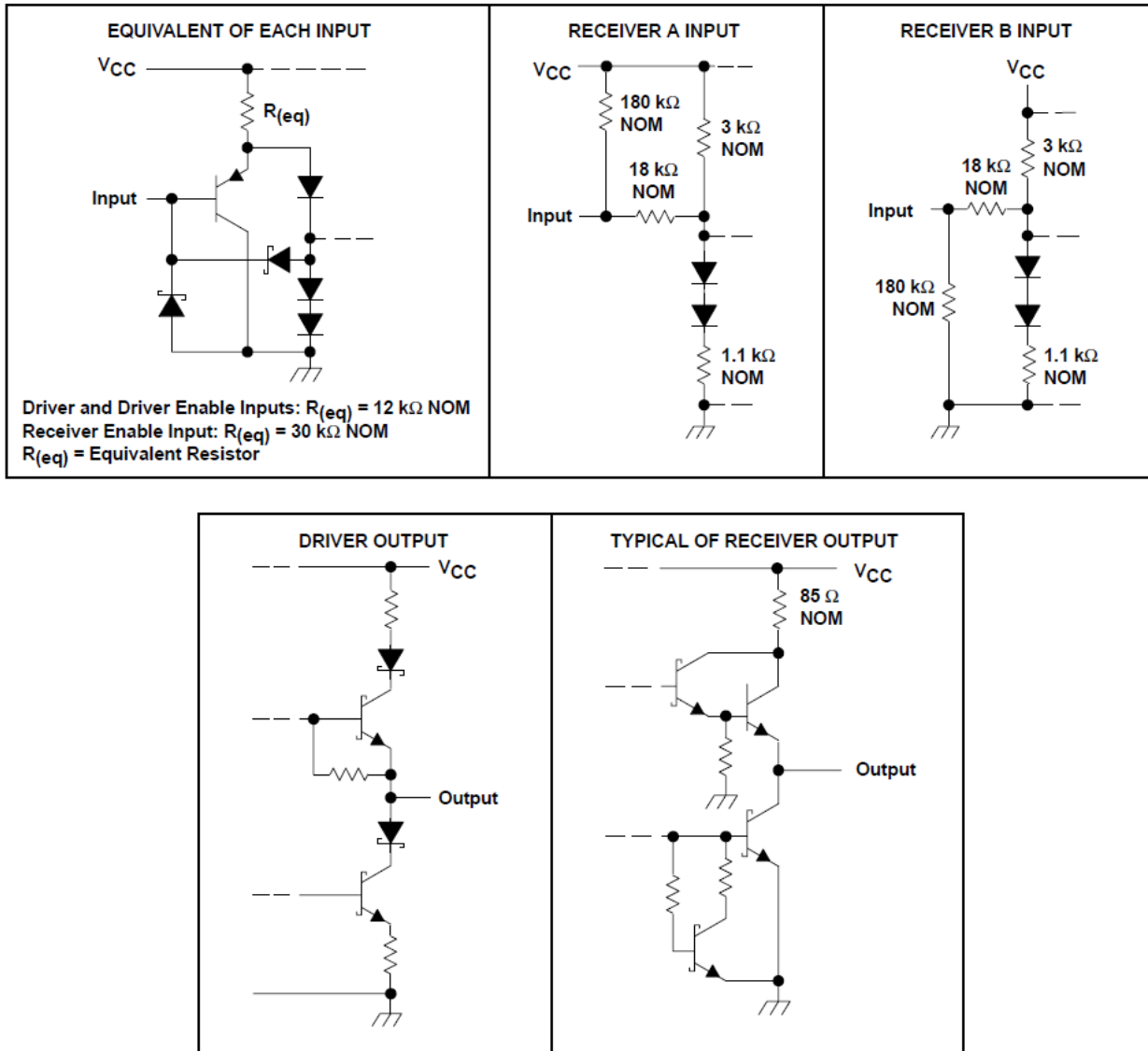


- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.

FIG 6-8. Receiver Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Functional Block Diagram



7-1. Schematic of Inputs and Outputs

7.2 Device Functional Modes

Function Tables

表 7-1. Driver⁽¹⁾

INPUT D	ENABLE DE	OUTPUTS	
		Y	Z
H	H	H	L
L	H	L	H
X	L	Z	Z

(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

表 7-2. Receiver⁽¹⁾

DIFFERENTIAL INPUTS A–B	ENABLE RE	OUTPUT R
$V_{ID} \geq 0.2 \text{ V}$	L	H
$-0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$	L	?
$V_{ID} \leq -0.2 \text{ V}$	L	L
X	H	Z
Open	L	H

(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

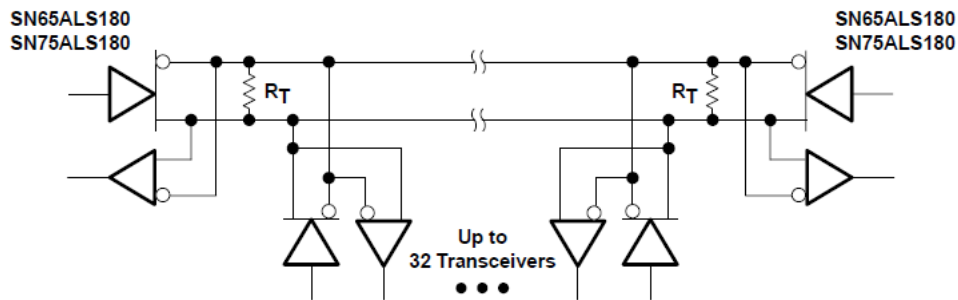
8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.2 Typical Application



- A. The line should terminate at both ends in its characteristic impedance ($R_T = Z_0$). Stub lengths off the main line should be kept as short as possible.

8-1. Typical Application Circuit

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.1.1 Related Documentation

9.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.com のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

9.3 サポート・リソース

[TI E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

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9.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65ALS180DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65ALS180	Samples
SN65ALS180DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65ALS180	Samples
SN75ALS180D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	0 to 70	75ALS180	
SN75ALS180DR	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	0 to 70	75ALS180	
SN75ALS180N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75ALS180N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65ALS180DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN65ALS180DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65ALS180DR	SOIC	D	14	2500	356.0	356.0	35.0
SN65ALS180DR	SOIC	D	14	2500	356.0	356.0	35.0

TUBE




*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN75ALS180N	N	PDIP	14	25	506	13.97	11230	4.32

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 -  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - D The 20 pin end lead shoulder width is a vendor option, either half or full width.

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